Docket Number: 061063-0356139

Client Reference: OSP-19398

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of MASATAKA HOURAI, et al.

Group Art Unit:

Application No.:

Examiner:

Filed: July 24, 2006

Confirmation No.:

For: SILICON WAFER, METHOD FOR MANUFACTURING THE SAME AND METHOD FOR GROWING SILICON SINGLE CRYSTALS

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR 1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom. Applicants respectfully request the Examiner return an initialed copy of the enclosed Form PTO-1449 to Applicants with the next Office communication to indicate that the references have been considered, per MPEP § 609.

This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of the first Office Action on the merits in the present application. No certification or fee is required.

English-language Abstracts of the non-English language references are attached hereto and are relied upon for a statement of relevance for the reference.

Respectfully Submitted,

PILLSBURY WINTHROP SHAW PITTMANLLEP

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P.O. Box 10500 McLean, VA 22102 Date: July 24, 2006

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PTO/SB/08a (07-05) Approved for use through 07/31/2006. OMB 0651-0031

U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE

Substitu	ite for form 1449A/PTO			Complete if Known		
				Application Number	10120/039	
INF	ORMATION I	DISCLO	SURE	Filing Date	07/24/2006	
STA	ATEMENT BY	/ APPLI	CANT	First Named Inventor	MASATAKA HOURAI	
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Sheet	2	of	2	Attorney Docket Number	061063-0356139	

			U. S. PATENT D	OCUMENTS	
Examiner Initials*	Cite No.1	Document Number Number-Kind Code ^{2 (d known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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	6	JP	2004-182525		07/02/2004	·		
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This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

IAP6 Rec'd PCT/PTO 24 JUL 2006

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Application Number

Filing Date

Substitute for form 1449B/PTO

Signature

INFORMATION DISCLOSURE

STAT	STATEMENT BY APPLICANT			First Named Inventor MASATAKA HOURAI					
					Art Unit				
	(Use as	many sheets as	necessary)	Examiner Name UNASSIGNED		GNED		
Sheet		1	of	1	Attorney Docket Number	061063-0	356139		
		<u>-</u>		NON PATE	NT LITERATURE DOCUMENTS	s			
Examiner Initials*	Cite No.1						T²		
	I.				en and Crystal Technology - controlling of ultimately light element," 110th ys., Div. Science and Technology of Crystals, p. 11-18, (6/3/1999).				
	II.				wing to Hydrogen in Si single crystals grown by continuously rials Science and Engineering, p. 146-149, B6 (1996).				
	III				carrier recombination centers in high-purity, dislocation-free, float-zoned microdefects," Jounal of Crystal Growth, p. 155-161, Vol. 109 (1991).				
	IV.				"X-Ray Observations of Defect Structures in Silicone Crystal," d Physics, Vol. 4 (No. 12), p. 962-972, (7/9/1965).				
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			U. S. PATENT	DOCUMENTS	
Examiner Initials*	Cite No.1	Document Number Number-Kind Code ^{2 (f known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevan Figures Appear
	1	US- 2002-139298 A1	10/03/2002	OKUI, ET AL.	
	2	^{US-} 2002-081440 A1	06/27/2002	MURAKAMI, ET AL.	
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Examiner Initials*	Cite No.¹	Country	Foreign Patent Document Code ³ Number ⁴ 'Kind Code ³ (if known)		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
	1	JP	2001-220289		08/14/2001	OKUI, ET AL.		
	2	JР	2002-187794		07/05/2002	MURAKAMI, ET AL.		
	3	JР	2000-281491	Α	10/10/2000	IKARI, ET AL.		
	4	JР	2001-335396		12/04/2001	VON AMMON, ET AL.		
	5	JР	2001-151597		06/05/2001			П

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